

SINEWAVE HF VCXO



ESD Sensitive

17.4 x 14.38 x 6.38 mm

Datasheet #0707A

Features

- Ultra Low Phase Noise and Jitter
- No Multiplication
- Absolute Pull Range (APR) to $\pm 1,000$ ppm
- SONET ± 20 ppm overall free-run stability available
- High Shock Resistance, to 1000g

Applications

- Fiber Channel
- 10 GbE
- Infiniband
- Network Processors
- SONET/SDH
- COTS/Dual use

Absolute Maximum Ratings

Parameters	Symbol	Condition	Min	Typ	Max	Unit	Notes
Operating Temperature Range	To		-40		+85	°C	
Storage Temperature Range	Tst		-50		+90	°C	
Supply Voltage	Vcc		-0.5		5.5	V	
Control Voltage	Vc		-0.5		5.5	V	

Electrical (1*)

Parameters	Symbol	Condition	Min	Typ	Max	Unit	Notes	
Nominal Frequency	Fo		12		250	MHz		
Supply Voltage	Vcc	Code 0 Code A	4.75 3.135	5.0 3.3	5.25 3.465	V		
Supply current	Icc	No load, Vcc=3.3V 100MHz		60	160	mA		
Output Logic Type				Sine				
Load		Internally AC coupled	45	50	55	Ohm		
Harmonic	Ph				-25	dBc		
Sub-Harmonics			None					
Output Power	Po	Into 50 ohm, 5V 3.3V	7 5	10 7		dBm		
Jitter	Integrated, RMS	J	Integrated from Phase Noise, 12KHz to 20MHz, RMS			0.1	0.15	ps
			100Hz to 80KHz, RMS				0.5	ps
			50KHz to 80MHz			0.2		ps
	Wavecrest characterized	J	Random period,		2.5		ps	
			Accumul., pk-to-pk		17		ps	
			Determin.		0		ps	

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Electrical (cont.)

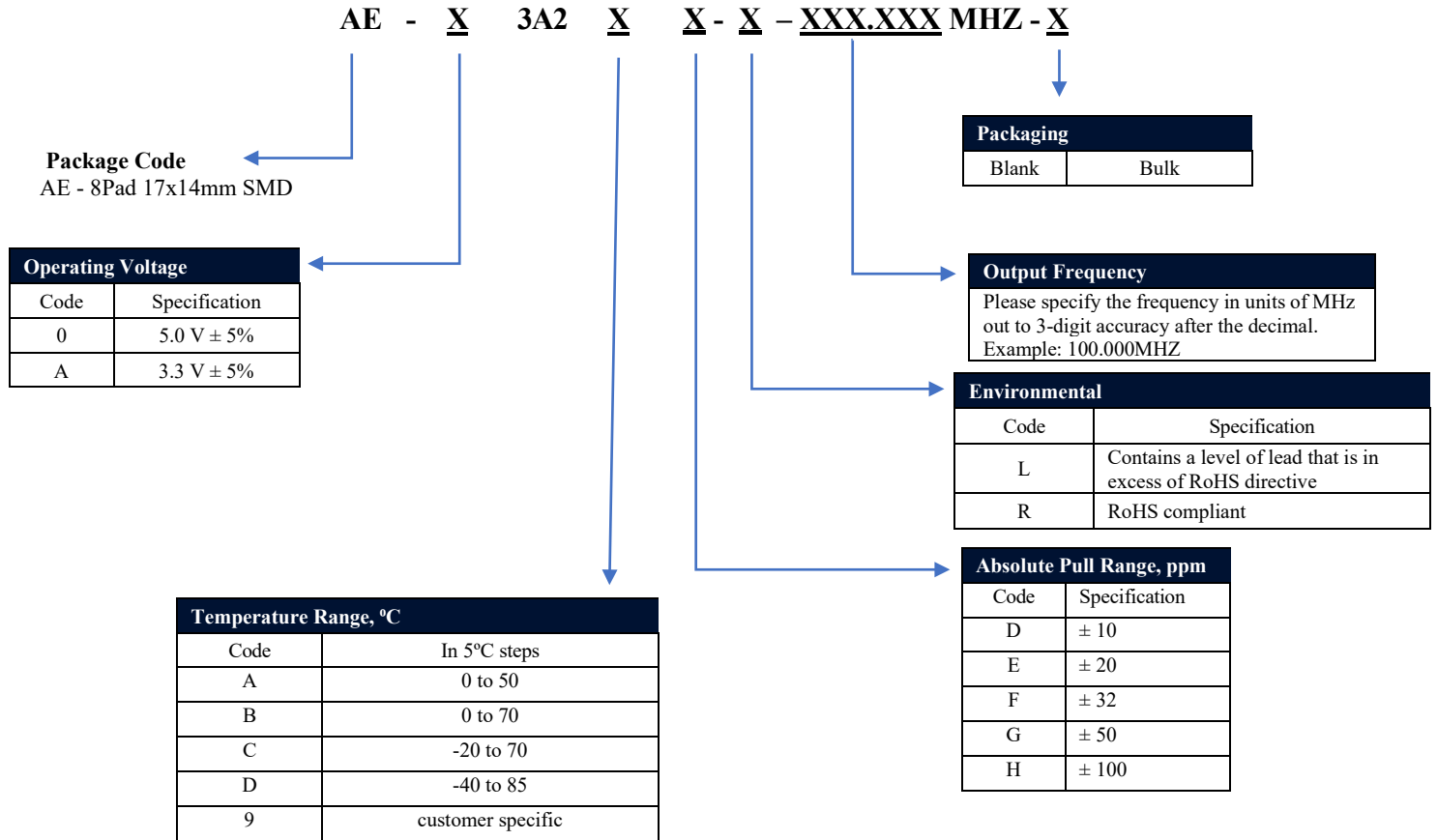
Parameters	Symbol	Condition	Min	Typ	Max	Unit	Notes
Phase Noise	$\mathcal{L}(\Delta f)$	100 MHz, 3.3V APR 32 ppm or less		@10Hz @100Hz @1KHz @10KHz @100KHz @>1MHz	-85 -115 -145 -166 -171 -172	dBc/Hz	
Frequency Stability, usually not specified – unless necessary, APR is specified to incorporate stability	$\Delta F/F$	Overall, including temperature, aging 10 years, shock and vibration @Vc=Vcc/2; APR 50 ppm, or less	±20	±30		ppm	
Control Voltage Range	Vc		0V		Vcc	V	
Setability	Vcs	Vc to set the F at Fo; T, Vcc, load – nominal, as shipped	0.4 Vcc	0.5 Vcc	0.6 Vcc	V	
Absolute Pull Range	APR	Over all conditions, see part # creation	10, 20, 32, 50, 100			ppm	
Input impedance	Zin	@ Fmod < 100 KHz	50			KOhm	
Modulation Bandwidth		At Vc = Vcc/2, -3dB	20			KHz	

Environmental and Mechanical

Parameter	Description
Operating temp. range	See part # table
Mechanical Shock	Per MIL-STD-202, Method 213, Cond. A
Thermal Shock	Per MIL-STD-883, Method 1011, Cond. A
Vibration	Per MIL-STD-883, Method 2007, Cond. A
Hermetic Seal	Leak rate less than 5×10^{-8} atm.cc/s of helium, crystal only.
Soldering conditions	See MAX reflow profile below; The device may be reflowed once. Reflowing upside down is not allowed. NO CLEAN assembly is recommended.



Creating a Part Number



Not all combinations are available. Consult Factory.

Temperature Code Table

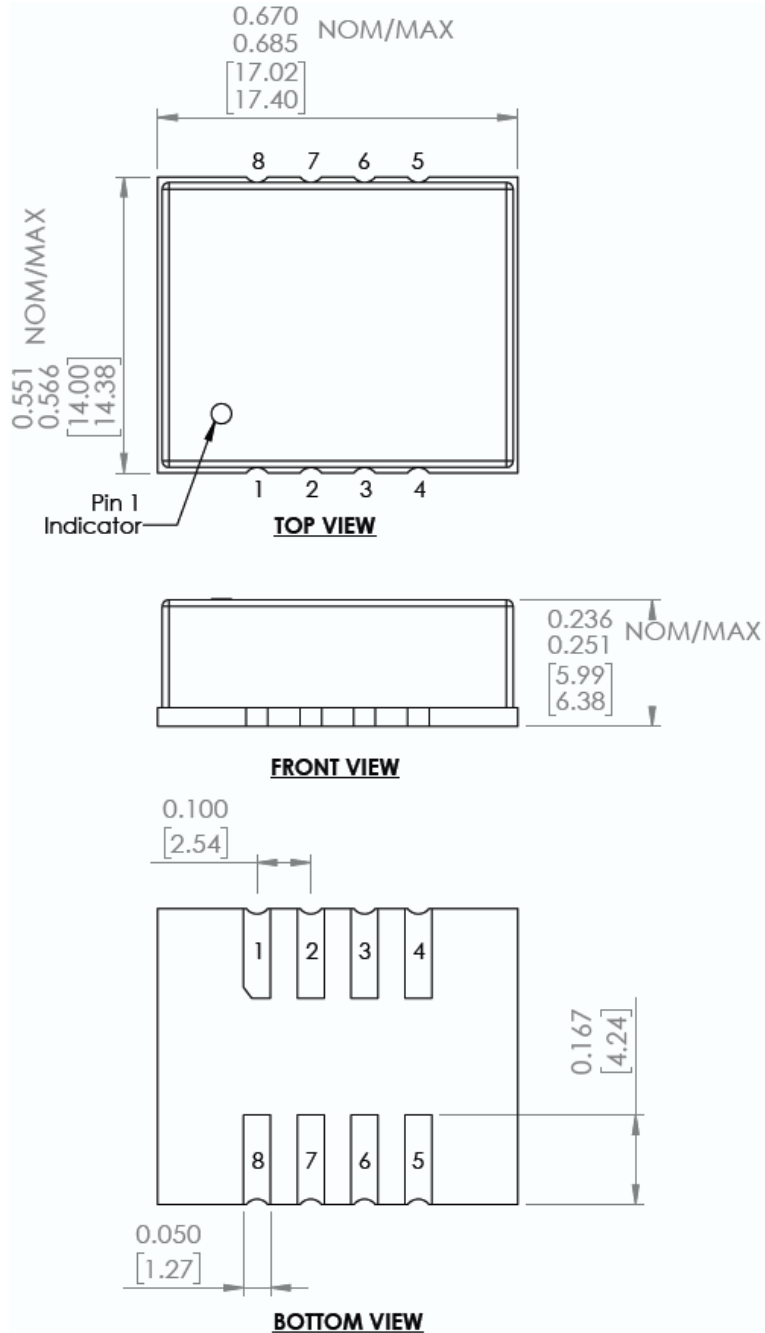
Letter	Temp °C	Letter	Temp °C	Letter	Temp °C	Letter	Temp °C	Letter	Temp °C	Letter	Temp °C
A	-40	F	-15	K	10	P	35	U	60	Z	85
B	-35	G	-10	L	15	Q	40	V	65		
C	-30	H	-5	M	20	R	45	W	70		
D	-25	I	0	N	25	S	50	X	75		
E	-20	J	5	O	30	T	55	Y	80		

Notes:

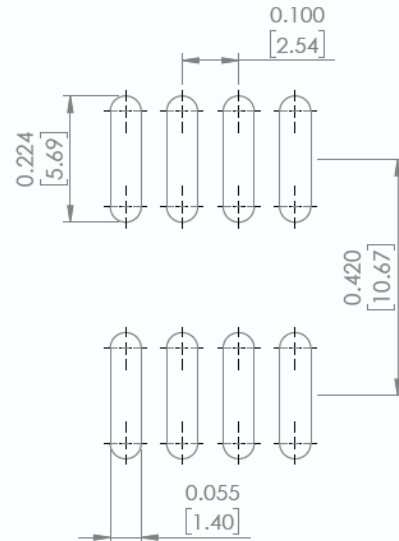
1* All Parameters, unless otherwise specified, are at nominal conditions; ie: T=25°C, Nominal Vcc & Nominal Load .



Mechanical Dimensions



Recommended Land Pattern



OUTLINE TOLERANCE:
±0.015 [0.40] (UNLESS OTHERWISE SPECIFIED)

Pin #	Function
1	Vcc
2	GND
3	GND
4	GND
5	OUTPUT
6	N/C
7	GND
8	Vc

Dimensions: inches [mm]

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Phase Noise Plot

Typical Phase Noise at 100 MHz





Reflow Profile [JEDEC J-STD-020]

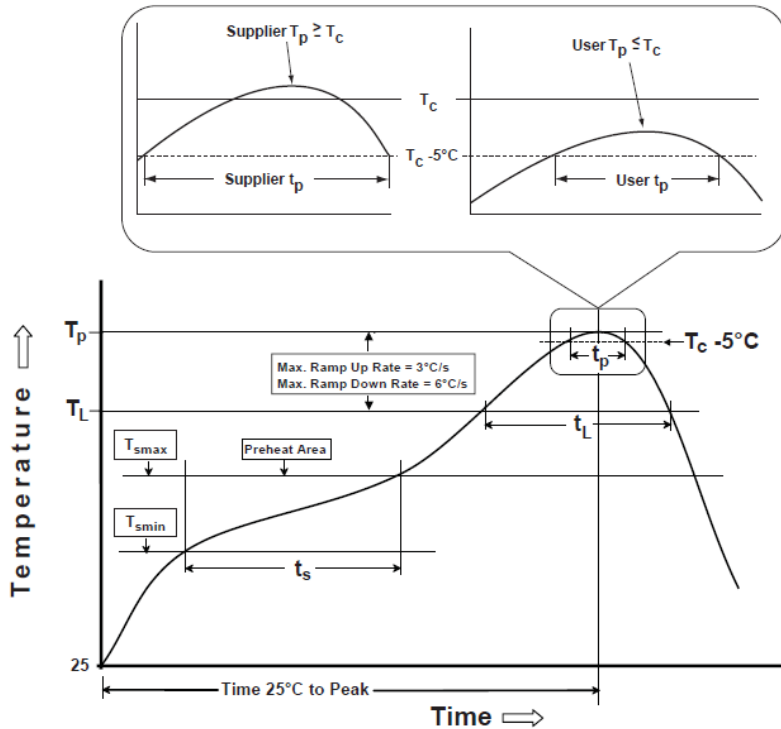


Table 1

SnPb Eutectic Process Classification Temperatures (T_c)		
Package Thickness	Volume mm^3 <350	Volume mm^3 \geq 350
<2.5 mm	235°C	220°C
\geq 2.5 mm	220°C	220°C

Table 2

Pb-Free Process Classification Temperatures (T_c)			
Package Thickness	Volume mm^3 <350	Volume mm^3 350-2000	Volume mm^3 >2000
<1.6 mm	260°C	260°C	260°C
1.6 mm - 2.5 mm	260°C	250°C	245°C
>2.5 mm	250°C	245°C	245°C

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat / soak		
Temperature minimum (T_{smin})	100°C	150°C
Temperature maximum (T_{smax})	150°C	200°C
Time (T_{smin} to T_{smax}) (t_s)	60 - 120 sec.	60 - 120 sec.
Average ramp-up rate (T_{smax} to T_p)	3°C/sec. max	3°C/sec. max
Liquidous temperature (T_L)	183°C	217°C
Time at liquidous (t_L)	60 - 150 sec.	60 - 150 sec.
Peak package body temperature (T_p)*	see Table 1	see Table 2
Time (t_p)** within 5°C of the specified classification temperature (T_c)	20 sec.	30 sec.
Ramp-down rate (T_p to T_{smax})	6°C/sec. max	6°C/sec. max
Time 25°C to peak temperature	6 min. max	8 min. max
Reflow cycles	1 max	1 max

*Tolerance for peak profile temperature (T_p) is defined as a supplier minimum and a user maximum.

**Tolerance for time at peak profile temperature (t_p) is defined as supplier minimum and a user maximum.